

## PI6C557-03

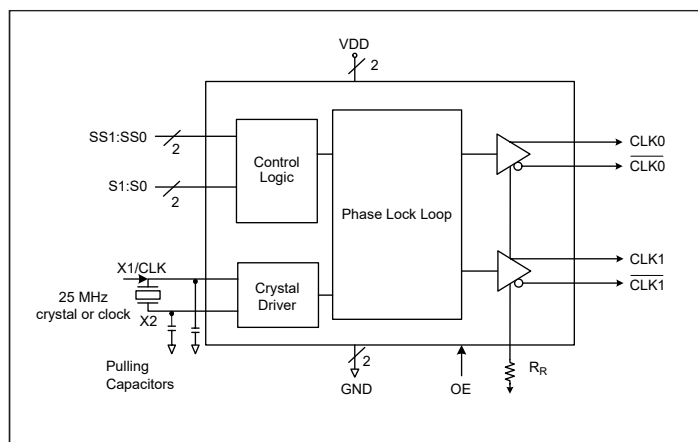
### PCI Express Clock

## Description

The PI6C557-03 is a spread spectrum clock generator supporting PCI Express and Ethernet requirements. The device is used for PC or embedded systems to substantially reduce Electromagnetic Interference (EMI).

The PI6C557-03 provides two differential (HCSL) spread spectrum outputs. The PI6C557-03 is configured to select spread and clock selection. Using Pericom's patented Phase-Locked Loop (PLL) techniques, the device takes a 25MHz crystal input and produces two pairs of differential outputs (HCSL) at 25MHz, 100MHz, 125MHz and 200MHz clock frequencies. It also provides spread selection of  $\pm 0.25\%$ ,  $-0.5\%$ ,  $-0.75\%$ , and no spread.

## Block Diagram



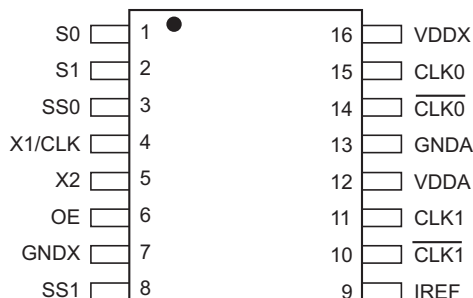
## Features

- LVDS Compatible Outputs
- Supply Voltage of 3.3V  $\pm 10\%$
- 25MHz Input Frequency
- HCSL Outputs, 0.7V Current Mode Differential Pair
- Jitter 60ps Cycle-to-cycle (typical)
- Spread of  $\pm 0.25\%$ ,  $-0.5\%$ ,  $-0.75\%$ , and No Spread
- Industrial Temperature Range
- Packaging: (Pb-free and Green)
  - 16-pin, TSSOP (L)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/quality/product-definitions/) or your local Diodes representative.

### Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## Pin Configuration



## Pin Description

Pin Number	Pin Name	I/O Type	Description
1	S0	Input	Select pin 0 (Internal pull-up resistor). See Table 1.
2	S1	Input	Select pin 1 (Internal pull-up resistor). See Table 1.
3	SS0	Input	Spread Select pin 0 (Internal pull-up resistor). See Table 2.
4	X1/CLK	Input	Crystal or clock input. Connect to a 25MHz crystal or single ended clock.
5	X2	Output	Crystal connection. Leave unconnected for clock input.
6	OE	Input	Output enable. Internal pull-up resistor.
7	GNDX	Power	Crystal ground pin.
8	SS1	Input	Spread Select pin 1 (Internal pull-up resistor). See Table 2.
9	IREF	Output	Precision resistor attached to this pin is connected to the internal current reference.
10	CLK1	Output	HCSL compliment clock output
11	CLK1	Output	HCSL clock output
12	VDDA	Power	Connect to a +3.3V source.
13	GNDA	Power	Output and analog circuit ground.
14	CLK0	Output	HCSL compliment clock output
15	CLK0	Output	HCSL clock output
16	VDDX	Power	Connect to a +3.3V source.

Table 1. Output Select Table

S1	S0	CLK(MHz)
0	0	25
0	1	100
1	0	125
1	1	200

Table 2. Spread Selection Table

SS1	SS0	Spread
0	0	Center $\pm 0.25$
0	1	Down -0.5
1	0	Down -0.75
1	1	No Spread

## Application Information

### Decoupling Capacitors

Decoupling capacitors of 0.01μF should be connected between each V<sub>DD</sub> pin and the ground plane and placed as close to the V<sub>DD</sub> pin as possible.

### Crystal

Use a 25MHz fundamental mode parallel resonant crystal with less than 300PPM of error across temperature.

### Crystal Capacitors

$C_L$  = Crystals's load capacitance in pF

Crystal Capacitors (pF) =  $(C_L - 8) * 2$

For example, for a crystal with 16pF load caps, the external effective crystal cap would be 16 pF.  $(16-8)*2=16$ .

### Current Source (Iref) Reference Resistor - R<sub>R</sub>

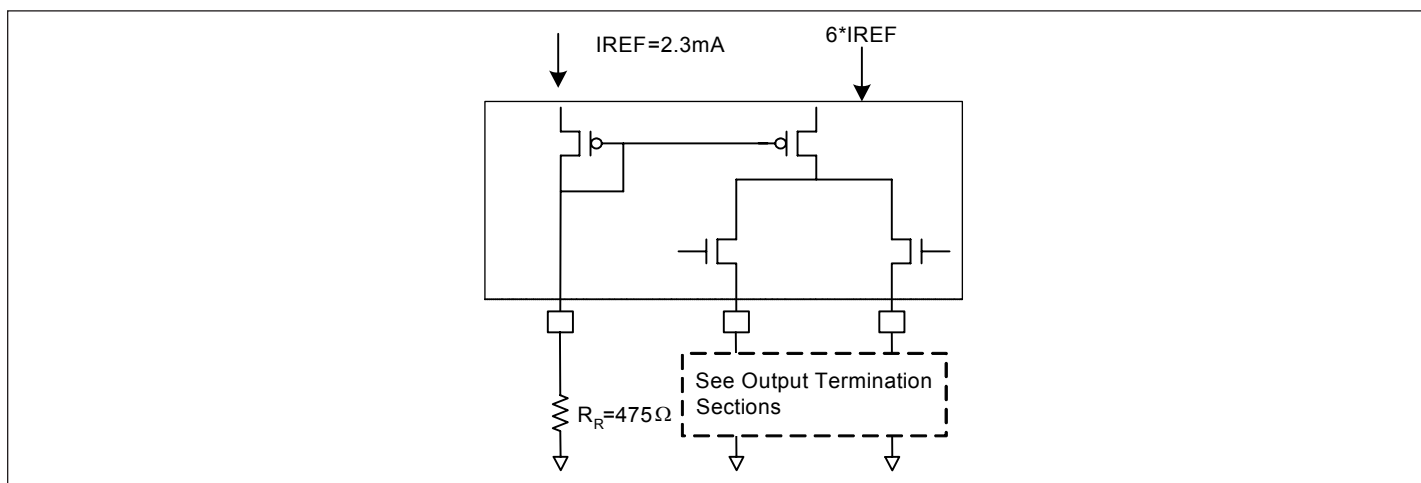
If board target trace impedance is 50Ω,

then  $R_R = 475\Omega$  providing an IREF of 2.32 mA. The output current (I<sub>OH</sub>) is 6\*IREF.

### Output Termination

The PCI Express differential clock outputs of the PI6C557-03 are open source drivers and require an external series resistor and a resistor to ground. These resistor values and their allowable locations are shown in detail in the PCI Express Layout Guidelines section.

The PI6C557-03 can be configured for LVDS compatible voltage levels. See the LVDS Compatible Layout Guidelines section.



**Figure 1. Output Structures**

### PCI Express Layout Guidelines

Common Recommendations for Differential Routing	Dimension or Value	Unit
L1 length, route as non-coupled 50Ω trace.	0.5 max	inch
L2 length, route as non-coupled 50Ω trace.	0.2 max	inch
L3 length, route as non-coupled 50Ω trace.	0.2 max	inch
R <sub>S</sub>	33	Ω
R <sub>T</sub>	49.9	Ω

Differential Routing on a Single PCB	Dimension or Value	Unit
L4 length, route as coupled microstrip 100Ω differential trace.	2 min to 16 max	inch
L4 length, route as coupled stripline 100Ω differential trace.	1.8 min to 14.4 max	inch

Differential Routing to a PCI Express connector	Dimension or Value	Unit
L4 length, route as coupled microstrip 100Ω differential trace.	0.25 min to 14 max	inch
L4 length, route as coupled stripline 100Ω differential trace.	0.225 min to 12.6 max	inch

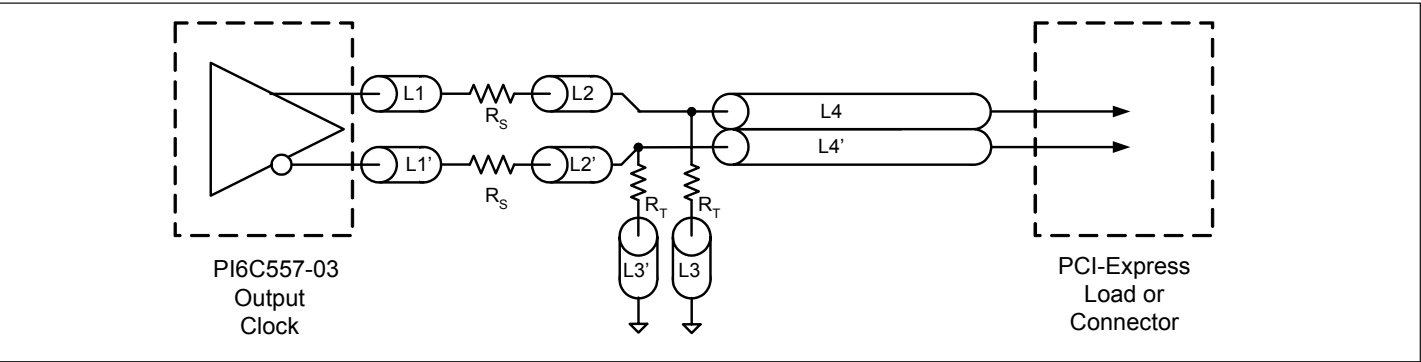


Figure 2. PCI Express Device Routing

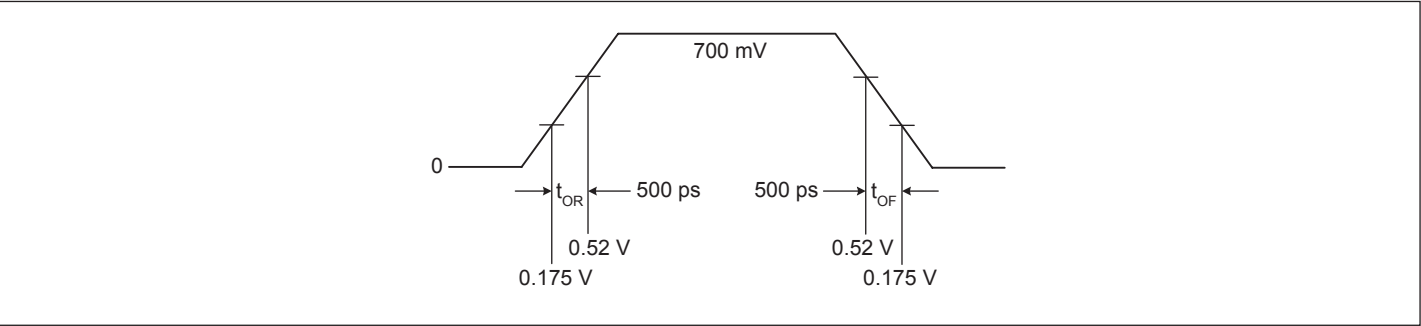


Figure 3. Typical PCI Express (HCSL) Waveform

# Application Information

LVDS Recommendations for Differential Routing	Dimension or Value	Unit
L1 length, route as non-coupled 50Ω trace.	0.5 max	inch
L2 length, route as non-coupled 50Ω trace.	0.2 max	inch
R <sub>P</sub>	100	Ω
R <sub>Q</sub>	100	Ω
R <sub>T</sub>	150	Ω
L3 length, route as 100Ω differential trace.		
L3 length, route as 100Ω differential trace.		

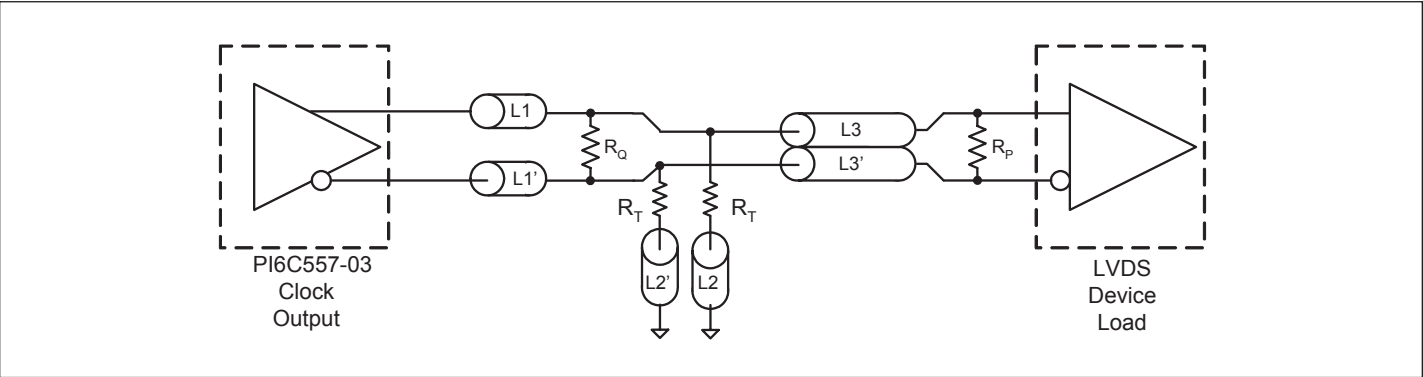


Figure 4. LVDS Device Routing

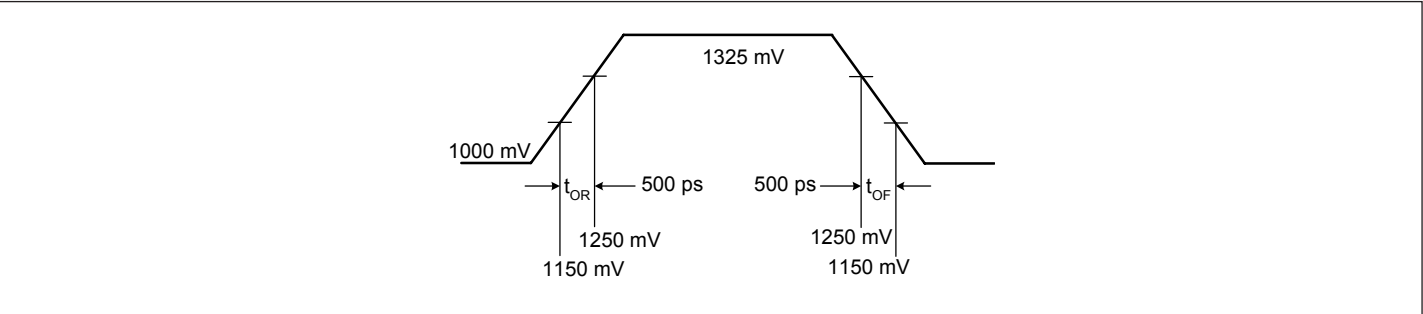


Figure 5. Typical LVDS Waveform

## Maximum Ratings

Supply Voltage to Ground Potential.....	5.5V
All Inputs and Outputs .....	-0.5V to $V_{DD}+0.5V$
Ambient Operating Temperature.....	-40 to +85°C
Storage Temperature.....	-65 to +150°C
Junction Temperature .....	150°C
Soldering Temperature .....	260°C

### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Recommended Operation Conditions

Parameter	Min.	Typ.	Max.	Unit
Ambient Operating Temperature	-40		+85	°C
Power Supply Voltage (measured in respect to GND)	+3.0		+3.6	V

## DC Characteristics

 $V_{DD} = 3.3V \pm 10\%$ ,  $T_A = -40^\circ C$  to  $+85^\circ C$ 

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$V_{DD}$	Supply Voltage		3.0	3.3	3.60	V
$V_{IH}$	Input High Voltage <sup>(1)</sup>	S0, S1, OE, CLK, SS0, SS1	2.0		$V_{DD} + 0.3$	V
$V_{IL}$	Input Low Voltage <sup>(1)</sup>	S0, S1, OE, CLK, SS0, SS1	GND - 0.3		0.8	V
$I_{IL}$	Input Leakage Current	$0 < V_{IN} < V_{DD}$	With input pull-up and pull-downs	-20	20	$\mu A$
			Without input pull-up and pull-downs	-5	5	
$I_{DD}$	Operating Supply Current	$R_L = 50\Omega$ , $C_L = 2pF$			95	mA
$I_{DDOE}$		OE = LOW			50	mA
$C_{IN}$	Input Capacitance	Input pin capacitance			7	pF
$C_{OUT}$	Output Capacitance	Output pin capacitance			6	pF
$L_{PIN}$	Pin Inductance				5	nH
$R_{OUT}$	Output Resistance	CLK Outputs	3.0			k $\Omega$

### Notes:

- Single edge is monotonic when transitioning through region.

## AC Characteristics

 $V_{DD} = 3.3V \pm 10\%$ ,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ 

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$F_{IN}$	Input Frequency			25		MHz
$V_{OUT}$	Output Frequency		25		200	MHz
$V_{OH}$	Output High Voltage <sup>(1,2)</sup>	@ $V_{DD} = 3.3V$	660	700	850	mV
$V_{OL}$	Output Low Voltage <sup>(1,2)</sup>		-150	0		mV
$V_{CPA}$	Crossing Point Voltage <sup>(1,2)</sup>	Absolute	250	350	550	mV
$V_{CN}$	Crossing Point Voltage <sup>(1,2,4)</sup>	Variation over all edges			140	mV
$J_{CC}$	Jitter, Cycle-to-Cycle <sup>(1,3)</sup>			60	100	ps
$M_F$	Modulation Frequency	Spread Spectrum	30	31.5	33	kHz
$t_{OR}$	Rise Time <sup>(1,2)</sup>	From 0.175V to 0.525V	175	332	700	ps
$t_{OF}$	Fall Time <sup>(1,2)</sup>	From 0.525V to 0.175V	175	344	700	ps
$\Delta T_R/\Delta T$	Rise/Fall Time Variation <sup>(1,2)</sup>				125	ps
$T_{SKEW}$	Skew between outputs	$V_{DD}/2$			50	ps
$T_{DUTY-CYCLE}$	Duty Cycle <sup>(1,3)</sup>		45		55	%
$T_{OE}$	Output Enable Time <sup>(5)</sup>	All outputs		0.1		$\mu s$
$T_{OT}$	Output Disable Time <sup>(5)</sup>	All outputs		0.1		$\mu s$
$t_{STABLE}$	From power-up to $V_{DD} = 3.3V$		1.6	3.0		ms
$t_{SPREAD}$	Setting period after spread change			3.0		ms
Error	Synthesizer Error	PLL locked, xtal load is matched and SSC off		0		ppm

Notes:

1.  $R_L = 50\Omega$  with  $C_L = 2pF$  and  $R_R = 475\Omega$
2. Single-ended waveform
3. Differential waveform
4. Measured at the crossing point
5. CLK pins are tri-stated when OE is LOW

## Thermal Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$\theta_{JA}$	Thermal Resistance Junction to Ambient	Still air			90	$^{\circ}C/W$
$\theta_{JC}$	Thermal Resistance Junction to Case				24	$^{\circ}C/W$

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## Recommended Crystal Specification

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Diodes recommends:

- a) GC2500003 XTAL 49S/SMD(4.0 mm), 25M, CL=18pF, +/-30ppm  
[http://www.pericom.com/pdf/datasheets/se/GC\\_GF.pdf](http://www.pericom.com/pdf/datasheets/se/GC_GF.pdf)
- b) FY2500081, SMD 5x3.2(4P), 25M, CL=18pF, +/-30ppm  
[http://www.pericom.com/pdf/datasheets/se/FY\\_F9.pdf](http://www.pericom.com/pdf/datasheets/se/FY_F9.pdf)
- c) FL2500047, SMD 3.2x2.5(4P), 25M, CL=18pF, +/-20ppm  
<https://www.diodes.com/datasheet/download/FL.pdf>



**PI6C557-03**

## Part Marking

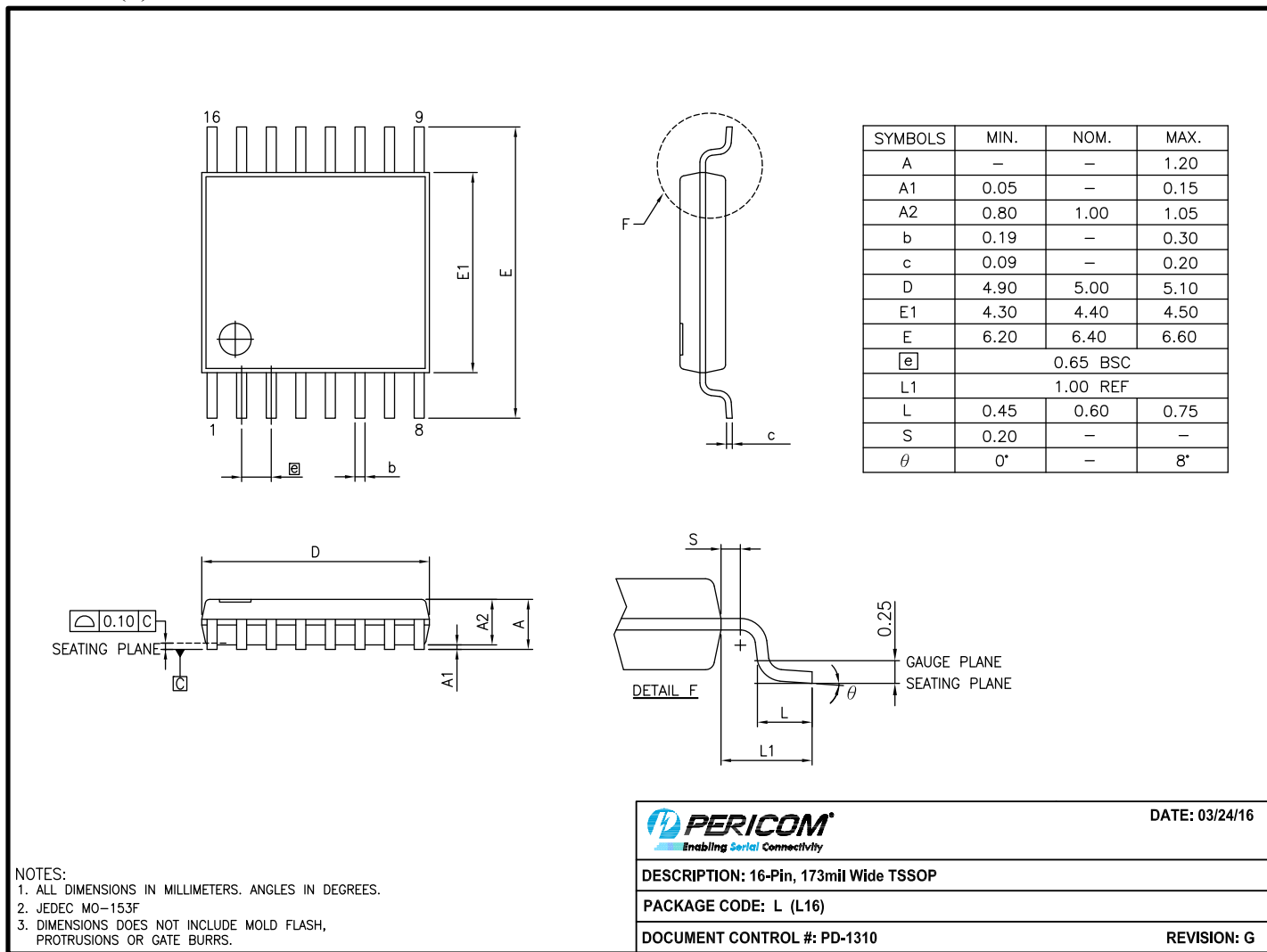
PI6C557  
-03LE  
YYYWWX<sup>̄</sup>X  
○

1st Y: Die Rev  
2nd & 3rd Y: Year  
WW: Workweek  
1st X: Assembly Code  
2nd X: Fab Code

**PI6C557-03**

## Packaging Mechanical

### 16-TSSOP (L)



16-0061

For latest package info.

 please check: <http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/>

## Ordering Information

Orderable Part Number	Package Code	Package Description
PI6C557-03LEX	L	16-Pin, 173mil Wide (TSSOP)

### Notes:

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- E = Pb-free and Green
- X suffix = Tape/Reel

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